

Positive voltage regulator ICs









TO-220FP





Features

- Output current up to 1.5 A
- Output voltages of 5; 6; 8; 8.5; 9; 12; 15; 18; 24 V
- Thermal overload protection
- Short circuit protection
- Output transition SOA protection
- 2 % output voltage tolerance (A version)
- Guaranteed in extended temperature range (A version)

Description

The L78 series of three-terminal positive regulators is available in TO-220, TO-220FP, D2PAK and DPAK packages and several fixed output voltages, making it useful in a wide range of applications.

These regulators can provide local on-card regulation, eliminating the distribution problems associated with single point regulation. Each type embeds internal current limiting, thermal shut-down and safe area protection, making it essentially indestructible. If adequate heat sinking is provided, they can deliver over 1 A output current. Although designed primarily as fixed voltage regulators, these devices can be used with external components to obtain adjustable voltage and currents.

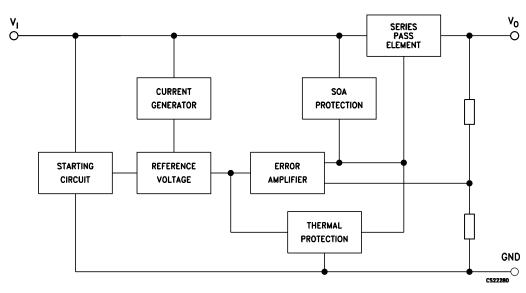
Maturity status link

L78



1 Diagram

Figure 1. Block diagram



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Pin configuration

Figure 2. Pin connections (top view)

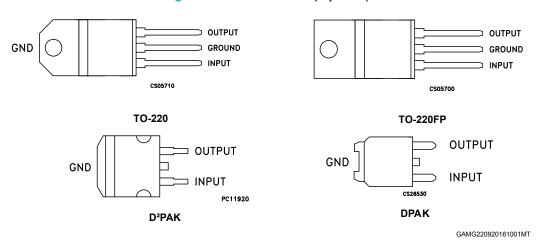
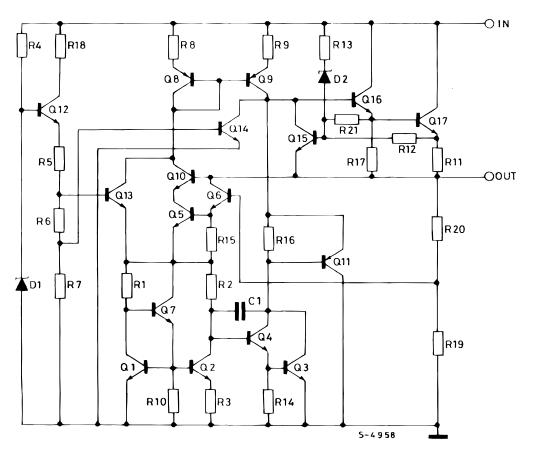


Figure 3. Schematic diagram



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3 Maximum ratings

Table 1. Absolute maximum ratings

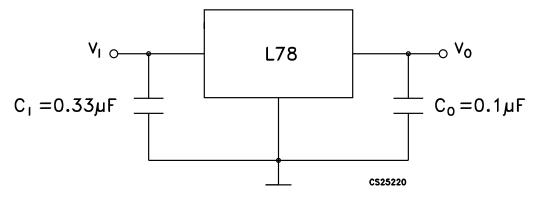
Symbol	Parameter		Value	Unit
W	DC input valte as	for V _O = 5 to 18 V	35	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
VI	DC input voltage	for V _O = 20, 24 V	40	V
Io	Output current	Internally limited		
P _D	Power dissipation		Internally limited	
T _{STG}	Storage temperature range		-65 to 150	°C
T _{OP}	Operating junction temperature range	for L78xxC, L78xxAC	0 to 125	°C
, OP	Operating junction temperature range	for L78xxAB	-40 to 125	

Note: Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

Table 2. Thermal data

Symbol	Parameter	D ² PAK	DPAK	TO-220	TO-220FP	Unit
R _{thJC}	Thermal resistance junction-case	3	8	5	5	°C/W
R _{thJA}	Thermal resistance junction-ambient	62.5	100	50	60	°C/W

Figure 4. Application circuits



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4 Test circuits

Figure 5. DC parameter

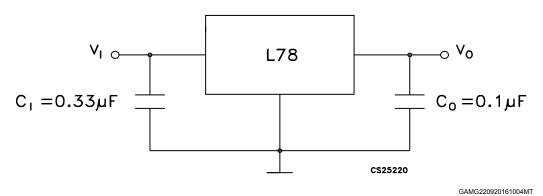


Figure 6. Load regulation

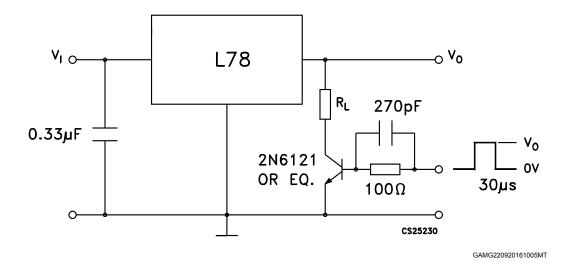
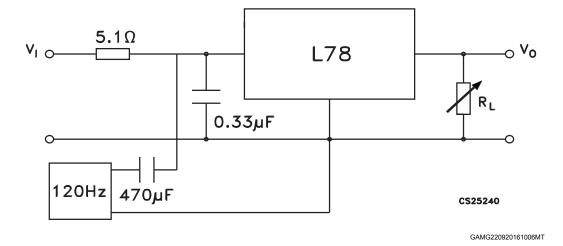


Figure 7. Ripple rejection



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5 Electrical characteristics

 V_I = 10 V, I_O = 1 A, T_J = 0 to 125 °C (L7805AC), T_J = -40 to 125 °C (L7805AB), unless otherwise specified.

Table 3. Electrical characteristics of L7805A

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
Vo	Output voltage	T _J = 25 °C	4.9	5	5.1	V
Vo	Output voltage	I _O = 5 mA to 1 A, V _I = 7.5 to 18 V	4.8	5	5.2	V
Vo	Output voltage	I_O = 1 A, V_I = 18 to 20 V, T_J = 25 °C	4.8	5	5.2	V
		V_I = 7.5 to 25 V, I_O = 500 mA, T_J = 25 °C		7	50	mV
AN (1)	Dan an and Alban	V _I = 8 to 12 V		10 50	50	mV
$\Delta V_{O}^{(1)}$	Line regulation	V _I = 8 to 12 V, T _J = 25 °C		2	25	mV
		V _I = 7.3 to 20 V, T _J = 25 °C		7	50	mV
		I _O = 5 mA to 1 A		25	100	mV
ΔV _O ⁽¹⁾	Load regulation	I _O = 5 mA to 1.5 A, T _J = 25 °C		30	100	
		I _O = 250 to 750 mA		8	50	
	Quiescent current	T _J = 25 °C		4.3	6	mA
Iq	Quiescent current				6	mA
		V _I = 8 to 23 V, I _O = 500 mA			0.8	mA
ΔI_{q}	Quiescent current change	V _I = 7.5 to 20 V, T _J = 25 °C			0.8	mA
		I _O = 5 mA to 1 A			0.5	mA
SVR	Supply voltage rejection	V _I = 8 to 18 V, f = 120 Hz, I _O = 500 mA		68		dB
V _d	Dropout voltage	I _O = 1 A, T _J = 25 °C		2		V
eN	Output noise voltage	T _A = 25 °C, B =10 Hz to 100 kHz		10		μV/V _O
R _O	Output resistance	f = 1 kHz		17		mΩ
I _{sc}	Short circuit current	V _I = 35 V, T _A = 25 °C		0.2		Α
I _{scp}	Short circuit peak current	T _J = 25 °C		2.2		Α
$\Delta V_O/\Delta T$	Output voltage drift			-1.1		mV/°C

^{1.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

Note: Minimum load current for regulation is 5 mA.

 V_I = 11 V, I_O = 1 A, T_J = 0 to 125 °C (L7806AC), T_J = -40 to 125 °C (L7806AB), unless otherwise specified.

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Table 4. Electrical characteristics of L7806A

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _O	Output voltage	T _J = 25 °C	5.88	6	6.12	V
Vo	Output voltage	I _O = 5 mA to 1 A, V _I = 8.6 to 19 V	5.76	6	6.24	V
Vo	Output voltage	I_{O} = 1 A, V_{I} = 19 to 21 V, T_{J} = 25 °C	5.76	6	6.24	V
		V_I = 8.6 to 25 V, I_O = 500 mA, T_J = 25 °C		9	60	mV
ΔV _O ⁽¹⁾	Line regulation	V _I = 9 to 13 V		11	60	mV
Δνοζ	Line regulation	V _I = 9 to 13 V, T _J = 25 °C		3	30	mV
		V _I = 8.3 to 21 V, T _J = 25 °C		9	60	mV
		I _O = 5 mA to 1 A		25	100	
ΔV _O ⁽¹⁾	Load regulation	I_O = 5 mA to 1.5 A, T_J = 25 °C		30	100	mV
		I _O = 250 to 750 mA		10	50	
ı	Quiescent current	T _J = 25° C		4.3	6	mA
Iq	Quiescent current				6	mA
		$V_1 = 9 \text{ to } 24 \text{ V}, I_0 = 500 \text{ mA}$			0.8	mA
Δl_{q}	Quiescent current change	V _I = 8.6 to 21 V, T _J = 25 °C			0.8	mA
		I _O = 5 mA to 1 A			0.5	mA
SVR	Supply voltage rejection	V _I = 9 to 19 V, f = 120 Hz, I _O = 500 mA		65		dB
V _d	Dropout voltage	I _O = 1 A, T _J = 25 °C		2		V
eN	Output noise voltage	T _A = 25 °C, B =10 Hz to 100 kHz		10		μV/V _O
R _O	Output resistance	f = 1 kHz		17		mΩ
I _{sc}	Short circuit current	V _I = 35 V, T _A = 25 °C		0.2		Α
I _{scp}	Short circuit peak current	T _J = 25 °C		2.2		Α
$\Delta V_{O}/\Delta T$	Output voltage drift			-0.8		mV/°C

^{1.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

 V_I = 14 V, I_O = 1 A, T_J = 0 to 125 °C (L7808AC), T_J = -40 to 125 °C (L7808AB), unless otherwise specified.

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Table 5. Electrical characteristics of L7808A

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
Vo	Output voltage	T _J = 25 °C	7.84	8	8.16	V
Vo	Output voltage	I_O = 5 mA to 1 A, V_I = 10.6 to 21 V	7.7	8	8.3	V
Vo	Output voltage	I_O = 1 A, V_I = 21 to 23 V, T_J = 25 °C	7.7	8	8.3	V
		V_I = 10.6 to 25 V, I_O = 500 mA, T_J = 25 °C		12	80	mV
A)/ (1)	Line menulation	V _I = 11 to 17 V		15	80	mV
$\Delta V_0^{(1)}$	Line regulation	V_I = 11 to 17 V, T_J = 25 °C		5	40	mV
		V_I = 10.4 to 23 V, T_J = 25 °C		12	80	mV
		I _O = 5 mA to 1 A		25	100	100 100 mV 50
ΔV _O ⁽¹⁾	Load regulation	I_O = 5 mA to 1.5 A, T_J = 25 °C		30	100	
		I _O = 250 to 750 mA		10	50	
	Quiescent current	T _J = 25 °C		4.3	6	mA
Iq	Quiescent current				6	mA
		V_{I} = 11 to 23 V, I_{O} = 500 mA			0.8	mA
ΔI_{q}	Quiescent current change	V_{I} = 10.6 to 23 V, T_{J} = 25 °C			0.8	mA
		I _O = 5 mA to 1 A			0.5	mA
SVR	Supply voltage rejection	V _I = 11.5 to 21.5 V, f = 120 Hz, I _O = 500 mA		62		dB
V _d	Dropout voltage	I _O = 1 A, T _J = 25 °C		2		V
eN	Output noise voltage	T_A = 25 °C, B =10 Hz to 100 kHz		10		μV/V _O
R _O	Output resistance	f = 1 kHz		18		mΩ
I _{sc}	Short circuit current	V _I = 35 V, T _A = 25 °C		0.2		Α
I _{scp}	Short circuit peak current	T _J = 25 °C		2.2		Α
$\Delta V_O/\Delta T$	Output voltage drift			-0.8		mV/°C

^{1.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

 V_I = 15 V, I_O = 1 A, T_J = 0 to 125 °C (L7809AC), T_J = -40 to 125 °C (L7809AB), unless otherwise specified(Minimum load current for regulation is 5 mA.)

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Table 6. Electrical characteristics of L7809A

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _O	Output voltage	T _J = 25 °C	8.82	9	9.18	V
Vo	Output voltage	I_O = 5 mA to 1 A, V_I = 11.5 to 22 V	8.65	9	9.35	V
Vo	Output voltage	I _O = 1 A, V _I = 22 to 24 V, T _J = 25 °C	8.65	9	9.35	V
		V_{I} = 10.6 to 25 V, I_{O} = 500 mA, T_{J} = 25 °C		12	90	mV
ΔV _O ⁽¹⁾	Line regulation	V _I = 11 to 17 V		15	90	mV
Δνοζ	Line regulation	V _I = 11 to 17 V, T _J = 25 °C		5	45	mV
		V _I = 11.4 to 23 V, T _J = 25 °C		12	90	mV
		I _O = 5 mA to 1 A		25	100	
$\Delta V_{O}^{~(1)}$	Load regulation	I_O = 5 mA to 1.5 A, T_J = 25 °C		30	100	mV
		I _O = 250 to 750 mA		10	50	
1	Quiescent current	T _J = 25 °C		4.3	6	mA
Iq	Quiescent current				6	mA
		V_{I} = 11 to 25 V, I_{O} = 500 mA			0.8	mA
ΔI_{q}	Quiescent current change	V _I = 10.6 to 23 V, T _J = 25 °C			0.8	mA
		I _O = 5 mA to 1 A			0.5	mA
SVR	Supply voltage rejection	V _I = 11.5 to 21.5 V, f = 120 Hz, I _O = 500 mA		61		dB
V _d	Dropout voltage	I _O = 1 A, T _J = 25 °C		2		V
eN	Output noise voltage	T_A = 25 °C, B =10 Hz to 100 kHz		10		μV/V _O
R _O	Output resistance	f = 1 kHz		18		mΩ
I _{sc}	Short circuit current	V _I = 35 V, T _A = 25 °C		0.2		Α
I _{scp}	Short circuit peak current	T _J = 25 °C		2.2		Α
$\Delta V_{O}/\Delta T$	Output voltage drift			-0.8		mV/°C

^{1.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

 V_I = 19 V, I_O = 1 A, T_J = 0 to 125 °C (L7812AC), T_J = -40 to 125 °C (L7812AB), unless otherwise specified.

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Table 7. Electrical characteristics of L7812A

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
Vo	Output voltage	T _J = 25 °C	11.75	12	12.25	V
Vo	Output voltage	I _O = 5 mA to 1 A, V _I = 14.8 to 25 V	11.5	12	12.5	V
Vo	Output voltage	I_O = 1 A, V_I = 25 to 27 V, T_J = 25 °C	11.5	12	12.5	V
		V_I = 14.8 to 30 V, I_O = 500 mA, T_J = 25 °C		13	120	mV
ΔV _O ⁽¹⁾	Line regulation	V _I = 16 to 12 V		16	120	mV
Δνο	Line regulation	V _I = 16 to 12 V, T _J = 25 °C		6	60	mV
		V _I = 14.5 to 27 V, T _J = 25 °C		13	120	mV
		I _O = 5 mA to 1 A		25	100	
$\Delta V_{O}^{(1)}$	Load regulation	I_O = 5 mA to 1.5 A, T_J = 25 °C		30	100	mV
		I _O = 250 to 750 mA		10	50	
1	Quiescent current	T _J = 25 °C		4.4	6	mA
Iq	Quiescent current				6	mA
		V_{I} = 15 to 30 V, I_{O} = 500 mA			0.8	mA
DI_q	Quiescent current change	V_I = 14.8 to 27 V, T_J = 25 °C			0.8	mA
		I _O = 5 mA to 1 A			0.5	mA
SVR	Supply voltage rejection	V _I = 15 to 25 V, f = 120 Hz, I _O = 500 mA		60		dB
V _d	Dropout voltage	I _O = 1 A, T _J = 25 °C		2		V
eN	Output noise voltage	T _A = 25 °C, B = 10 Hz to 100 kHz		10		μV/V _O
R _O	Output resistance	f = 1 kHz		18		mΩ
I _{sc}	Short circuit current	V _I = 35 V, T _A = 25 °C		0.2		Α
I _{scp}	Short circuit peak current	T _J = 25 °C		2.2		Α
$\Delta V_{O}/\Delta T$	Output voltage drift			-1		mV/°C

^{1.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

 V_I = 23 V, I_O = 1 A, T_J = 0 to 125 °C (L7815AC), T_J = -40 to 125 °C (L7815AB), unless otherwise specified.

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Table 8. Electrical characteristics of L7815A

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _O	Output voltage	T _J = 25 °C	14.7	15	15.3	V
Vo	Output voltage	I_O = 5 mA to 1 A, V_I = 17.9 to 28 V	14.4	15	15.6	V
Vo	Output voltage	I_{O} = 1 A, V_{I} = 28 to 30 V, T_{J} = 25 °C	14.4	15	15.6	V
		V_I = 17.9 to 30 V, I_O = 500 mA, T_J = 25 °C		13	150	mV
ΔV _O ⁽¹⁾	Line regulation	V _I = 20 to 26 V		16	150	mV
Δνοζ	Line regulation	V_I = 20 to 26 V, T_J = 25 °C		6	75	mV
		V _I = 17.5 to 30 V, T _J = 25 °C		13	150	mV
		I _O = 5 mA to 1 A		25	100	
$\Delta V_{O}^{(1)}$	Load regulation	I_O = 5 mA to 1.5 A, T_J = 25 °C		30	100	mV
		I _O = 250 to 750 mA		10	50	
	Quiescent current	T _J = 25 °C		4.4	6	mA
Iq	Quiescent current				6	mA
		V _I = 17.5 to 30 V, I _O = 500 mA			0.8	mA
ΔI_q	Quiescent current change	V_{I} = 17.5 to 30 V, T_{J} = 25 °C			0.8	mA
		I _O = 5 mA to 1 A			0.5	mA
SVR	Supply voltage rejection	V _I = 18.5 to 28.5 V, f = 120 Hz, I _O = 500 mA		58		dB
V _d	Dropout voltage	I _O = 1 A, T _J = 25 °C		2		V
eN	Output noise voltage	T_A = 25 °C, B = 10Hz to 100 kHz		10		μV/V _O
R _O	Output resistance	f = 1 kHz		19		mΩ
I _{sc}	Short circuit current	V _I = 35 V, T _A = 25 °C		0.2		Α
I _{scp}	Short circuit peak current	T _J = 25 °C		2.2		Α
$\Delta V_O/\Delta T$	Output voltage drift			-1		mV/°C

^{1.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

 V_I = 33 V, I_O = 1 A, T_J = 0 to 125 °C (L7824AC), T_J = -40 to 125 °C (L7824AB), unless otherwise specified.

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Table 9. Electrical characteristics of L7824A

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
Vo	Output voltage	T _J = 25 °C	23.5	24	24.5	V
Vo	Output voltage	I _O = 5 mA to 1 A, V _I = 27.3 to 37 V	23	24	25	V
Vo	Output voltage	I _O = 1 A, V _I = 37 to 38 V, T _J = 25 °C	23	24	25	V
		V_I = 27 to 38 V, I_O = 500 mA, T_J = 25 °C		31	240	mV
AV (1)		V _I = 30 to 36 V		35 200	200	mV
$\Delta V_{O}^{(1)}$	Line regulation	V _I = 30 to 36 V, T _J = 25 °C		14	120	mV
		V _I = 26.7 to 38 V, T _J = 25 °C		31	240	mV
		I _O = 5 mA to 1 A		25	100	
ΔV _O ⁽¹⁾	Load regulation	I _O = 5 mA to 1.5 A, T _J = 25 °C		30	100	mV
		I _O = 250 to 750 mA		10	50	
	Ouissant summer	T _J = 25 °C		4.6	6	mA
Iq	Quiescent current				6	mA
		V _I = 27.3 to 38 V, I _O = 500 mA			0.8	mA
Δl_{q}	Quiescent current change	V _I = 27.3 to 38 V, T _J = 25 °C			0.8	mA
		I _O = 5 mA to 1 A			0.5	mA
SVR	Supply voltage rejection	V _I = 28 to 38 V, f = 120 Hz, I _O = 500 mA		54		dB
V _d	Dropout voltage	I _O = 1 A, T _J = 25 °C		2		V
eN	Output noise voltage	T _A = 25 °C, B = 10 Hz to 100 kHz		10		μV/V _O
R _O	Output resistance	f = 1 kHz		20		m
I _{sc}	Short circuit current	V _I = 35 V, T _A = 25 °C		0.2		Α
I _{scp}	Short circuit peak current	T _J = 25 °C		2.2		Α
ΔV _O /ΔΤ	Output voltage drift			-1.5		mV/°C

^{1.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

Refer to the test circuits, T_J = 0 to 125 °C, V_I = 10 V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified.

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Table 10. Electrical characteristics of L7805C

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
Vo	Output voltage	T _J = 25 °C	4.8	5	5.2	V
Vo	Output voltage	I_O = 5 mA to 1 A, V_I = 7 to 18 V	4.75	5	5.25	V
Vo	Output voltage	I_{O} = 1 A, V_{I} = 18 to 20V, T_{J} = 25 °C	4.75	5	5.25	V
AV (1)	l in a manual attack	V_I = 7 to 25 V, T_J = 25 °C		3	100	
ΔV _O ⁽¹⁾	Line regulation	V_I = 8 to 12 V, T_J = 25 °C		1	50	mV
AV (1)	Lood nonviolation	I_{O} = 5 mA to 1.5 A, T_{J} = 25 °C			100	
ΔV _O ⁽¹⁾	Load regulation	I_{O} = 250 to 750 mA, T_{J} = 25 °C			50	mV
I _d	Quiescent current	T _J = 25° C			8	mA
41	Quiescent current change	I _O = 5 mA to 1 A			0.5	mA
Δl_d		V _I = 7 to 23 V			0.8	
$\Delta V_{O}/\Delta T$	Output voltage drift	I _O = 5 mA		-1.1		mV/°C
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		40		μV/V _O
SVR	Supply voltage rejection	V _I = 8 to 18 V, f = 120 Hz	62			dB
V _d	Dropout voltage	I _O = 1 A, T _J = 25 °C		2		V
R _O	Output resistance	f = 1 kHz		17		mΩ
I _{sc}	Short circuit current	V_I = 35 V, T_J = 25 °C		0.75		Α
I _{scp}	Short circuit peak current	T _J = 25 °C		2.2		Α

Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

Refer to the test circuits, T_J = 0 to 125 °C, V_I = 11 V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified.

Table 11. Electrical characteristics of L7806C

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
Vo	Output voltage	T _J = 25 °C	5.75	6	6.25	V

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Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
Vo	Output voltage	$I_O = 5 \text{ mA to 1 A}, V_I = 8 \text{ to 19 V}$	5.7	6	6.3	V
Vo	Output voltage	I_{O} = 1 A, V_{I} = 19 to 21 V, T_{J} = 25 °C	5.7	6	6.3	V
AV. (1)	Line regulation	V_I = 8 to 25 V, T_J = 25 °C			120	mV
ΔV _O ⁽¹⁾		V_I = 9 to 13 V, T_J = 25 °C			60	mv
AV (1)	l and an addition	I_O = 5 mA to 1.5 A, T_J = 25 °C			120	>/
ΔV_0 (1)	Load regulation	I_{O} = 250 to 750 mA, T_{J} = 25 °C			60	mV
I _d	Quiescent current	T _J = 25 °C			8	mA
DI	Quiescent current change	I _O = 5 mA to 1 A			0.5	
Dl _d		V _I = 8 to 24 V			1.3	mA
$\Delta V_O/\Delta T$	Output voltage drift	I _O = 5 mA		-0.8		mV/°C
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		45		μV/V _O
SVR	Supply voltage rejection	V _I = 9 to 19 V, f = 120 Hz	59			dB
V _d	Dropout voltage	I _O = 1 A, T _J = 25 °C		2		V
R _O	Output resistance	f = 1 kHz		19		mΩ
I _{sc}	Short circuit current	V _I = 35 V, T _J = 25 °C		0.55		Α
I _{scp}	Short circuit peak current	T _J = 25 °C		2.2		Α

Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

Refer to the test circuits, T_J = 0 to 125 °C, V_I = 14 V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified.

Table 12. Electrical characteristics of L7808C

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
Vo	Output voltage	T _J = 25 °C	7.7	8	8.3	V

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Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
Vo	Output voltage	I_{O} = 5 mA to 1 A, V_{I} = 10.5 to 21 V	7.6	8	8.4	V
Vo	Output voltage	I_O = 1 A, V_I = 21 to 25 V, T_J = 25 °C	7.6	8	8.4	V
AV. (1)	l in a namulation	V_I = 10.5 to 25 V, T_J = 25 °C			160	>/
$\Delta V_0^{(1)}$	Line regulation	V_I = 11 to 17 V, T_J = 25 °C			80	mV
A) ((1)	1 1 1 6	I_O = 5 mA to 1.5 A, T_J = 25 °C			160	.,
ΔV_0 ⁽¹⁾	Load regulation	I_O = 250 to 750 mA, T_J = 25 °C			80	mV
I _d	Quiescent current	T _J = 25 °C			8	mA
4.1	Quiescent current change	I _O = 5 mA to 1 A			0.5	
$\Delta l_{\sf d}$		V _I = 10.5 to 25 V			1	mA
$\Delta V_O/\Delta T$	Output voltage drift	I _O = 5 mA		-0.8		mV/°C
eN	Output noise voltage	B = 10 Hz to 100 kHz, T _J = 25 °C		52		μV/V _O
SVR	Supply voltage rejection	V _I = 11.5 to 21.5 V, f = 120 Hz	56			dB
V _d	Dropout voltage	I _O = 1 A, T _J = 25 °C		2		V
R _O	Output resistance	f = 1 kHz		16		mΩ
I _{sc}	Short circuit current	V _I = 35 V, T _J = 25 °C		0.45		Α
I _{scp}	Short circuit peak current	T _J = 25 °C		2.2		Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

Refer to the test circuits, T_J = 0 to 125 °C, V_I = 14.5 V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified.

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Table 13. Electrical characteristics of L7885C

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
Vo	Output voltage	T _J = 25 °C	8.2	8.5	8.8	V
Vo	Output voltage	I _O = 5 mA to 1 A, V _I = 11 to 21.5 V	8.1	8.5	8.9	V
Vo	Output voltage	I_{O} = 1 A, V_{I} = 21.5 to 26 V, T_{J} = 25 °C	8.1	8.5	8.9	V
AV. (1)	l in a manufation	V _I = 11 to 27 V, T _J = 25 °C			160	mV
ΔV _O ⁽¹⁾	Line regulation	V _I = 11.5 to 17.5 V, T _J = 25 °C			80	mv
AV. (1)	Lood regulation	I_O = 5 mA to 1.5 A, T_J = 25 °C			160	mV
ΔV _O ⁽¹⁾	Load regulation	I _O = 250 to 750 mA, T _J = 25 °C			80	mv
I _d	Quiescent current	T _J = 25 °C			8	mA
A.I.	Quiescent current change	I _O = 5 mA to 1 A			0.5	
ΔI_d		V _I = 11 to 26 V			1	mA
ΔV _O /ΔΤ	Output voltage drift	I _O = 5 mA		-0.8		mV/°C
eN	Output noise voltage	B = 10 Hz to 100 kHz, T _J = 25 °C		55		μV/V _O
SVR	Supply voltage rejection	V _I = 12 to 22 V, f = 120 Hz	56			dB
V _d	Dropout voltage	I _O = 1 A, T _J = 25 °C		2		V
R _O	Output resistance	f = 1 kHz		16		mΩ
I _{sc}	Short circuit current	V _I = 35 V, T _J = 25 °C		0.45		Α
I _{scp}	Short circuit peak current	T _J = 25 °C		2.2		Α

Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

Refer to the test circuits, T_J = 0 to 125 °C, V_I = 15 V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified.

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Table 14. Electrical characteristics of L7809C

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _O	Output voltage	T _J = 25 °C	8.64	9	9.36	V
V _O	Output voltage	I_{O} = 5 mA to 1 A, V_{I} = 11.5 to 22 V	8.55	9	9.45	V
V _O	Output voltage	I_{O} = 1 A, V_{I} = 22 to 26 V, T_{J} = 25 °C	8.55	9	9.45	V
ΔV _O ⁽¹⁾	Lina vanulation	V_I = 11.5 to 26 V, T_J = 25 °C			180	mV
Δνο	Line regulation	V_I = 12 to 18 V, T_J = 25 °C			90	mv
AN (1)		I_O = 5 mA to 1.5 A, T_J = 25 °C			180	>/
ΔV _O ⁽¹⁾	Load regulation	I_{O} = 250 to 750 mA, T_{J} = 25 °C			90	mV
I _d	Quiescent current	T _J = 25 °C			8	mA
41	Quiescent current change	I _O = 5 mA to 1 A			0.5	
ΔI_{d}		V _I = 11.5 to 26 V			1	mA
$\Delta V_{O}/\Delta T$	Output voltage drift	I _O = 5 mA		-1		mV/°C
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		70		μV/V _O
SVR	Supply voltage rejection	V _I = 12 to 23 V, f = 120 Hz	55			dB
V _d	Dropout voltage	I _O = 1 A, T _J = 25 °C		2		V
R _O	Output resistance	f = 1 kHz		17		mΩ
I _{sc}	Short circuit current	V_I = 35 V, T_J = 25 °C		0.40		Α
I _{scp}	Short circuit peak current	T _J = 25 °C		2.2		Α

Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

Refer to the test circuits, T_J = 0 to 125 °C, V_I = 19 V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified.

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Table 15. Electrical characteristics of L7812C

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _O	Output voltage	T _J = 25 °C	11.5	12	12.5	V
Vo	Output voltage	I_O = 5 mA to 1 A, V_I = 14.5 to 25 V	11.4	12	12.6	V
Vo	Output voltage	I_O = 1 A, V_I = 25 to 27 V, T_J = 25 °C	11.4	12	12.6	V
ΔV _O ⁽¹⁾	Line regulation	V_I = 14.5 to 30 V, T_J = 25 °C			240	mV
Δνο	Line regulation	V_I = 16 to 22 V, T_J = 25 °C			120	IIIV
ΔV _O ⁽¹⁾	Load regulation	I_O = 5 mA to 1.5 A, T_J = 25 °C			240	mV
Δνοζ	Load regulation	I_{O} = 250 to 750 mA, T_{J} = 25 °C			120	IIIV
I _d	Quiescent current	T _J = 25 °C			8	mA
41	Quiescent current change	I _O = 5 mA to 1 A			0.5	^
$\Delta l_{\sf d}$		V _I = 14.5 to 30 V			1	mA
$\Delta V_{O}/\Delta T$	Output voltage drift	I _O = 5 mA		-1		mV/°C
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		75		μV/V _O
SVR	Supply voltage rejection	V _I = 15 to 25 V, f = 120 Hz	55			dB
V _d	Dropout voltage	I _O = 1 A, T _J = 25 °C		2		V
R _O	Output resistance	f = 1 kHz		18		mΩ
I _{sc}	Short circuit current	V_I = 35 V, T_J = 25 °C		0.35		Α
I _{scp}	Short circuit peak current	T _J = 25 °C		2.2		Α

Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

Refer to the test circuits, T_J = 0 to 125 °C, V_I = 23 V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified.

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Table 16. Electrical characteristics of L7815C

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _O	Output voltage	T _J = 25 °C	14.4	15	15.6	V
Vo	Output voltage	$I_O = 5 \text{ mA to 1 A}, V_I = 17.5 \text{ to 28 V}$	14.25	15	15.75	V
Vo	Output voltage	I _O = 1 A, V _I = 28 to 30 V, T _J = 25 °C	14.25	15	15.75	V
AV (1)	l in a manufation	V _I = 17.5 to 30 V, T _J = 25 °C			300	mV
ΔV _O ⁽¹⁾	Line regulation	V _I = 20 to 26 V, T _J = 25 °C			150	mv
AV (1)	Lood regulation	I_O = 5 mA to 1.5 A, T_J = 25 °C			300	m)/
ΔV _O ⁽¹⁾	Load regulation	I _O = 250 to 750 mA, T _J = 25 °C			150	mV
I _d	Quiescent current	T _J = 25 °C			8	mA
41	Quiescent current change	I _O = 5 mA to 1A			0.5	
Δl _d		V _I = 17.5 to 30 V			1	mA
$\Delta V_O/\Delta T$	Output voltage drift	I _O = 5 mA		-1		mV/°C
eN	Output noise voltage	B = 10 Hz to 100kHz, T _J = 25 °C		90		μV/V _O
SVR	Supply voltage rejection	V _I = 18.5 to 28.5 V, f = 120 Hz	54			dB
V _d	Dropout voltage	I _O = 1 A, T _J = 25 °C		2		V
R _O	Output resistance	f = 1 kHz		19		mΩ
I _{sc}	Short circuit current	V _I = 35 V, T _J = 25 °C		0.23		Α
I _{scp}	Short circuit peak current	T _J = 25 °C		2.2		Α

Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

Refer to the test circuits, T_J = 0 to 125 °C, V_I = 26 V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified.

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Table 17. Electrical characteristics of L7818C

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _O	Output voltage	T _J = 25 °C	17.3	18	18.7	V
V _O	Output voltage	$I_O = 5 \text{ mA to } 1 \text{ A}, V_I = 21 \text{ to } 31 \text{ V}$	17.1	18	18.9	V
Vo	Output voltage	I_{O} = 1 A, V_{I} = 31 to 33 V, T_{J} = 25 °C	17.1	18	18.9	V
ΔV _O ⁽¹⁾	Line regulation	V _I = 21 to 33 V, T _J = 25 °C			360	mV
Δν ₀ (7)	Line regulation	V _I = 24 to 30 V, T _J = 25 °C			180	IIIV
ΔV _O ⁽¹⁾	Load regulation	I_O = 5 mA to 1.5 A, T_J = 25 °C			360	mV
Δνο ('')	Load regulation	I_{O} = 250 to 750 mA, T_{J} = 25 °C			180	IIIV
I _d	Quiescent current	T _J = 25 °C			8	mA
A1.	Quiescent current change	I _O = 5 mA to 1 A			0.5	^
$\Delta l_{\sf d}$		V _I = 21 to 33 V			1	mA
$\Delta V_{O}/\Delta T$	Output voltage drift	I _O = 5 mA		-1		mV/°C
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		110		μV/V _O
SVR	Supply voltage rejection	V _I = 22 to 32 V, f = 120 Hz	53			dB
V _d	Dropout voltage	I _O = 1 A, T _J = 25 °C		2		V
R _O	Output resistance	f = 1 kHz		22		mΩ
I _{sc}	Short circuit current	V_I = 35 V, T_J = 25 °C		0.20		Α
I _{scp}	Short circuit peak current	T _J = 25 °C		2.1		Α

Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

Refer to the test circuits, T_J = 0 to 125 °C, V_I = 33 V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified.

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Table 18. Electrical characteristics of L7824C

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _O	Output voltage	T _J = 25 °C	23	24	25	V
Vo	Output voltage	I_{O} = 5 mA to 1 A, V_{I} = 27 to 37 V	22.8	24	25.2	V
Vo	Output voltage	I_O = 1 A, V_I = 37 to 38 V, T_J = 25 °C	22.8	24	25.2	V
AV. (1)	Line regulation	V_I = 27 to 38 V, T_J = 25 °C			480	mV
ΔV _O ⁽¹⁾	Line regulation	V_I = 30 to 36 V, T_J = 25 °C			240	mv
AV (1)	I and assuitation	I_O = 5 mA to 1.5 A, T_J = 25 °C			480	mV
ΔV _O ⁽¹⁾	Load regulation	I_{O} = 250 to 750 mA, T_{J} = 25 °C			240	mv
I _d	Quiescent current	T _J = 25 °C			8	mA
A.I.	Quiescent current change	I _O = 5 mA to 1 A			0.5	4
ΔI_{d}		V _I = 27 to 38 V			1	mA
$\Delta V_{O}/\Delta T$	Output voltage drift	I _O = 5 mA		-1.5		mV/°C
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		170		μV/V _O
SVR	Supply voltage rejection	V _I = 28 to 38 V, f = 120 Hz	50			dB
V _d	Dropout voltage	I _O = 1 A, T _J = 25 °C		2		V
R _O	Output resistance	f = 1 kHz		28		mΩ
I _{sc}	Short circuit current	V _I = 35 V, T _J = 25° C		0.15		Α
I _{scp}	Short circuit peak current	T _J = 25 °C		2.1		Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

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6 Application information

6.1 Design consideration

The L78 Series of fixed voltage regulators are designed with thermal overload protection that shuts down the circuit when subjected to an excessive power overload condition, internal short-circuit protection that limits the maximum current the circuit will pass, and output transistor safe-area compensation that reduces the output short-circuit current as the voltage across the pass transistor is increased. In many low current applications, compensation capacitors are not required. However, it is recommended that the regulator input be bypassed with capacitor if the regulator is connected to the power supply filter with long lengths, or if the output load capacitance is large. An input bypass capacitor should be selected to provide good high frequency characteristics to insure stable operation under all load conditions. A 0.33 μ F or larger tantalum, mylar or other capacitor having low internal impedance at high frequencies should be chosen. The bypass capacitor should be mounted with the shortest possible leads directly across the regulators input terminals. Normally good construction techniques should be used to minimize ground loops and lead resistance drops since the regulator has no external sense

The addition of an operational amplifier allows adjustment to higher or intermediate values while retaining regulation characteristics. The minimum voltage obtained with the arrangement is 2 V greater than the regulator voltage.

The circuit of Figure 13. High current voltage regulator can be modified to provide supply protection against short circuit by adding a short circuit sense resistor, RSC, and an additional PNP transistor. The current sensing PNP must be able to handle the short circuit current of the three terminal regulator Therefore a four ampere plastic power transistor is specified.

 $V_{1} \circ U_{0} \circ U_{0$

Figure 8. Fixed output regulator

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- 1. Although no output capacitor is need for stability, it does improve transient response.
- 2. Required if regulator is located an appreciable distance from power supply filter.

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Figure 9. Current regulator

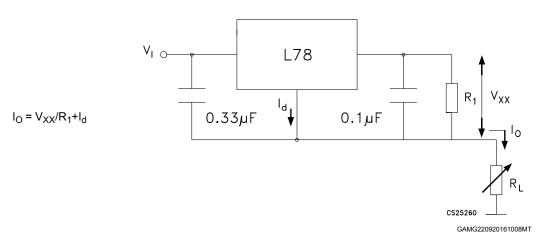


Figure 10. Circuit for increasing output voltage

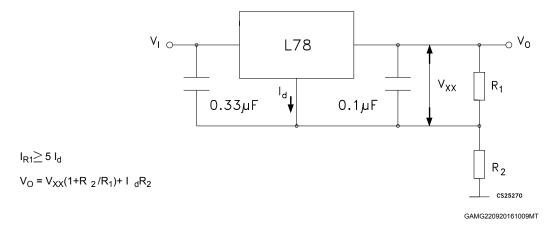
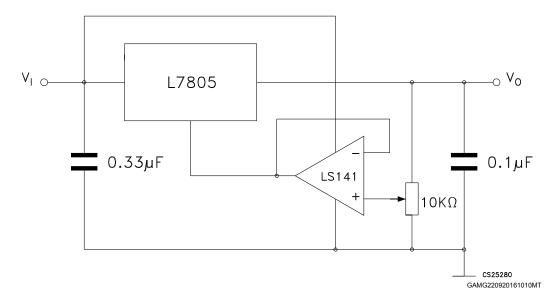


Figure 11. Adjustable output regulator (7 to 30 V)



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Figure 12. 0.5 to 10 V regulator

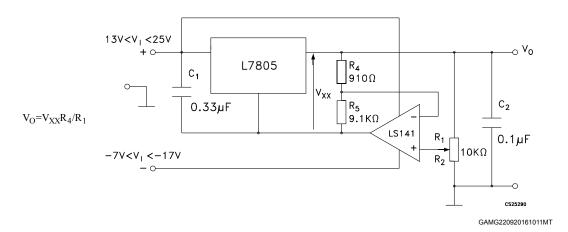


Figure 13. High current voltage regulator

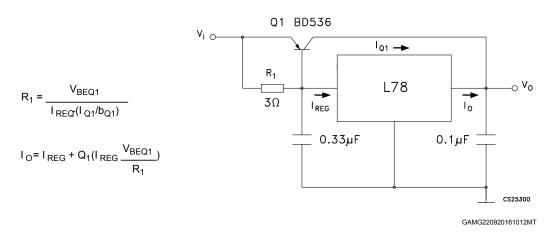
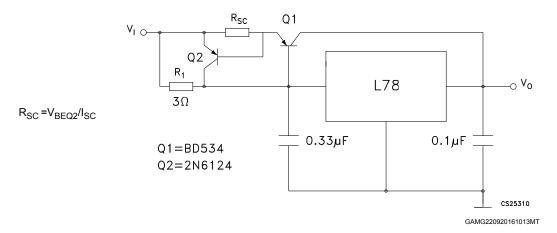


Figure 14. High output current with short circuit protection

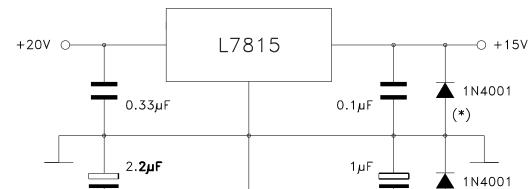


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Figure 15. Tracking voltage regulator

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L7915

CS25410

Figure 16. Split power supply (± 15 V - 1 A)

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→ 15V

Note: * Against potential latch-up problems.

-20V O

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Figure 17. Negative output voltage circuit

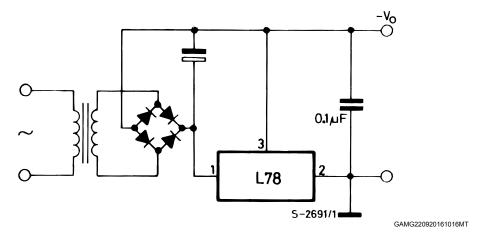


Figure 18. Switching regulator

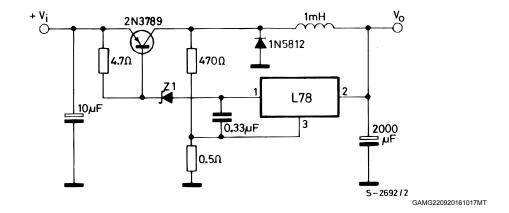
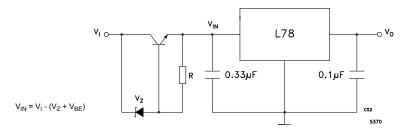


Figure 19. High input voltage circuit (configuration 1)

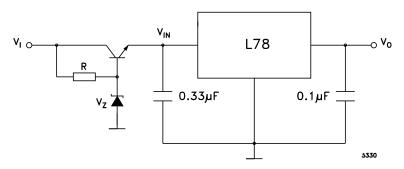


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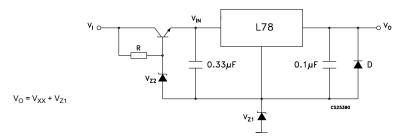


Figure 20. High input voltage circuit (configuration 2)



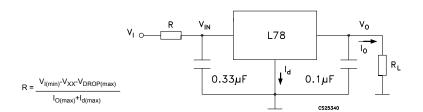
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Figure 21. High input and output voltage



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Figure 22. Reducing power dissipation with dropping resistor

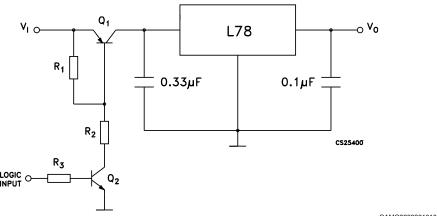


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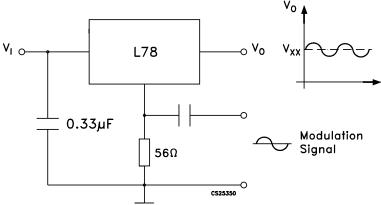


Figure 23. Remote shutdown



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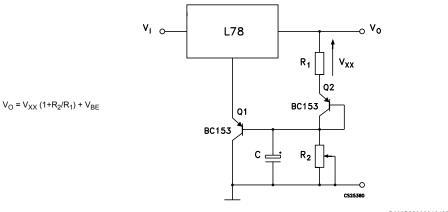
Figure 24. Power AM modulator (unity voltage gain, $I_0 \le 0.5$)



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Note: The circuit performs well up to 100 kHz.

Figure 25. Adjustable output voltage with temperature compensation



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Note: Q_2 is connected as a diode in order to compensate the variation of the Q_1 V_{BE} with the temperature. C allows a slow rise time of the V_O .

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Figure 26. Light controllers $(V_{O(min)} = V_{XX} + V_{BE})$

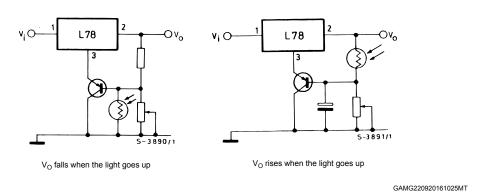
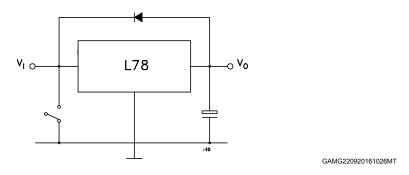


Figure 27. Protection against input short-circuit with high capacitance loads

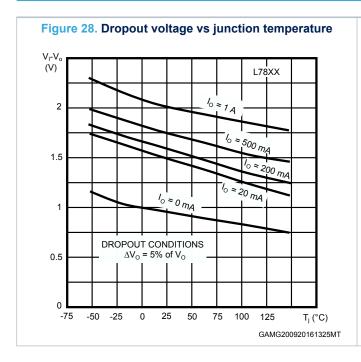


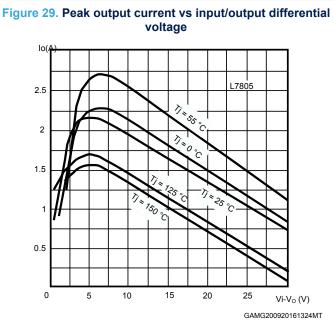
Note: Application with high capacitance loads and an output voltage greater than 6 volts need an external diode (see Figure 22. Reducing power dissipation with dropping resistor) to protect the device against input short circuit. In this case the input voltage falls rapidly while the output voltage decrease slowly. The capacitance discharges by means of the base-emitter junction of the series pass transistor in the regulator. If the energy is sufficiently high, the transistor may be destroyed. The external diode by-passes the current from the IC to ground.

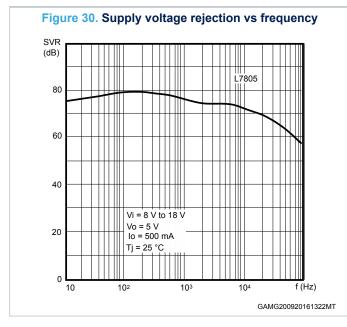
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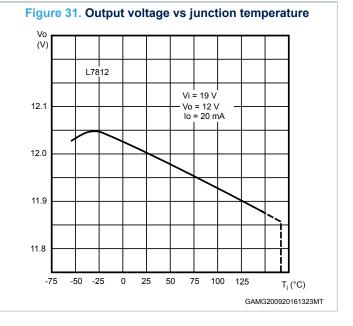


7 Typical performance









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Figure 32. Output impedance vs frequency

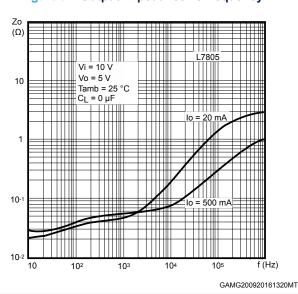


Figure 33. Quiescent current vs junction temp.

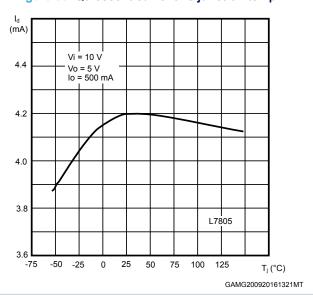


Figure 34. Load transient response

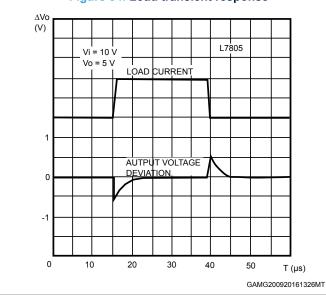


Figure 35. Line transient response

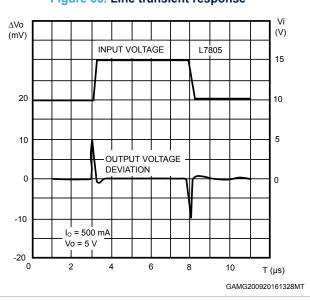
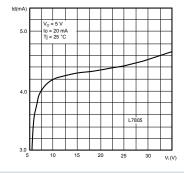


Figure 36. Quiescent current vs. input voltage



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8 Package information

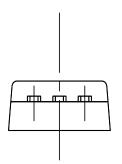
To meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions, and product status are available at: www.st.com. ECOPACK is an ST trademark.

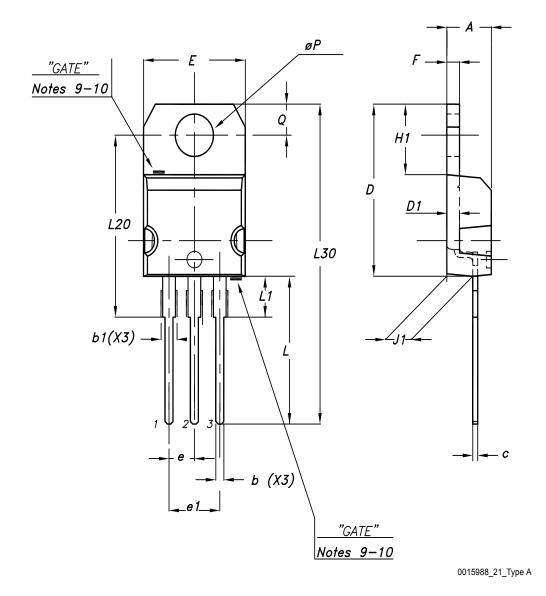
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8.1 TO-220 (dual gauge) package information

Figure 37. TO-220 (dual gauge) package outline





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Table 19. TO-220 (dual gauge) mechanical data

Dim		mm	
Dim.	Min.	Тур.	Max.
Α	4.40		4.60
b	0.61		0.88
b1	1.14		1.70
С	0.48		0.70
D	15.25		15.75
D1		1.27	
E	10		10.40
е	2.40		2.70
e1	4.95		5.15
F	1.23		1.32
H1	6.20		6.60
J1	2.40		2.72
L	13		14
L1	3.50		3.93
L20		16.40	
L30		28.90	
ØP	3.75		3.85
Q	2.65		2.95

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8.2 TO-220 (single gauge) package information

Figure 38. TO-220 (single gauge) package outline

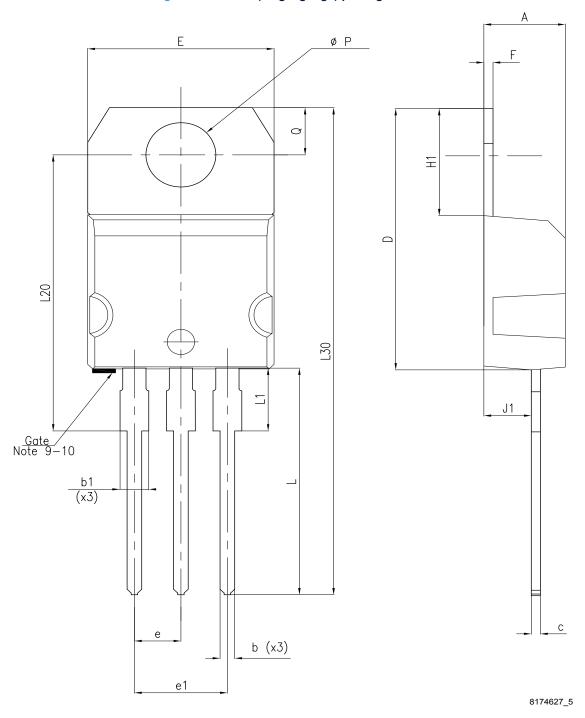


Table 20. TO-220 (single gauge) mechanical data

	Dim.	mm				
		Min.	Тур.	Max.		
	Α	4.40		4.60		

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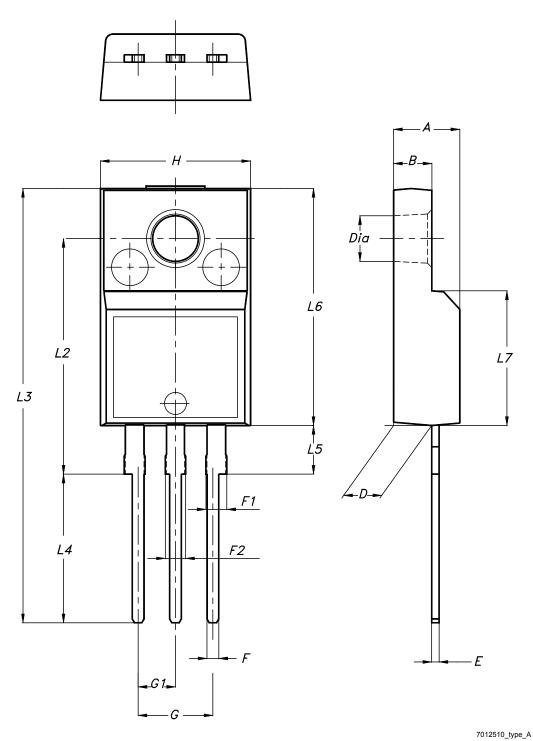
Dim.	mm					
Dim.	Min.	Тур.	Max.			
b	0.61		0.88			
b1	1.14		1.70			
С	0.48		0.70			
D	15.25		15.75			
E	10.00		10.40			
е	2.40		2.70			
e1	4.95		5.15			
F	0.51		0.60			
H1	6.20		6.60			
J1	2.40		2.72			
L	13.00		14.00			
L1	3.50		3.93			
L20		16.40				
L30		28.90				
ØP	3.75		3.85			
Q	2.65		2.95			

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8.3 TO-220FP type A package information

Figure 39. TO-220FP package outline



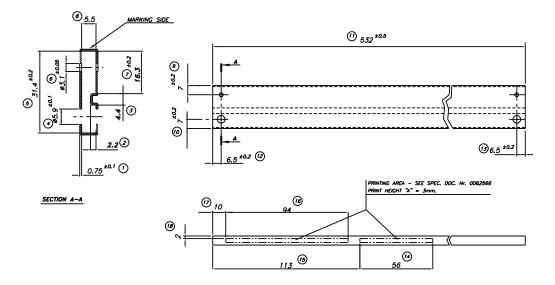
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Dim.	mm		
Dim.	Min.	Тур.	Max.
Α	4.4		4.6
В	2.5		2.7
D	2.5		2.75
E	0.45		0.7
F	0.75		1
F1	1.15		1.70
F2	1.15		1.70
G	4.95		5.2
G1	2.4		2.7
Н	10		10.4
L2		16	
L3	28.6		30.6
L4	9.8		10.6
L5	2.9		3.6
L6	15.9		16.4
L7	9		9.3
Dia	3		3.2

8.4 TO-220 (single/dual) packing information

Figure 40. Tube for TO-220 (dual gauge) (mm.)



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5.0±0.2

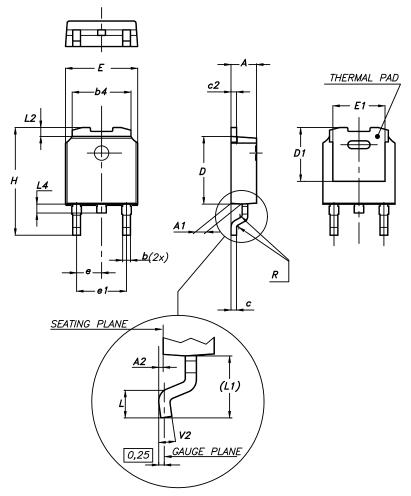
O 10.0

O 10.

Figure 41. Tube for TO-220 (single gauge) (mm.)

8.5 DPAK package information

Figure 42. DPAK package outline



0068772_A_21

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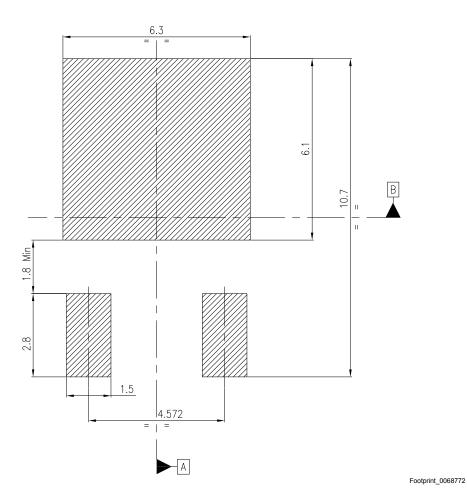
Table 22. DPAK mechanical data

Dim.	mm		
Dilli.	Min.	Тур.	Max.
А	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
С	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1		5.10	
E	6.40		6.60
E1		4.70	
е		2.28	
e1	4.40		4.60
Н	9.35		10.10
L	1.00		1.50
(L1)		2.80	
L2		0.80	
L4	0.60		1.00
R		0.20	
V2	0°		8°

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Figure 43. DPAK recommended footprint (dimensions are in mm)

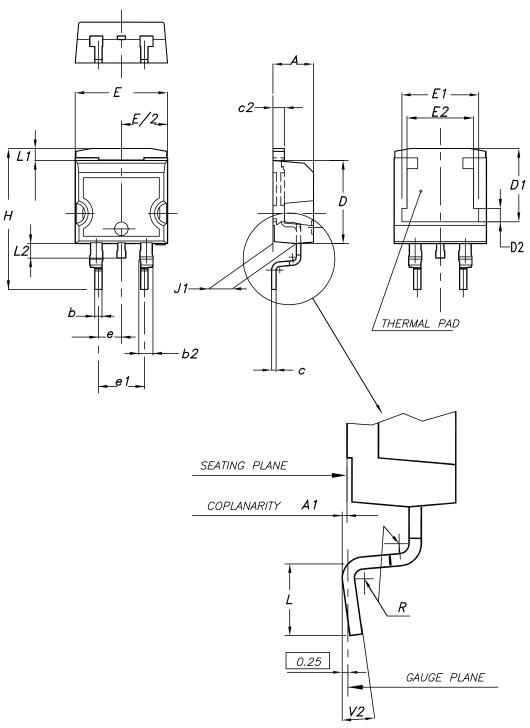


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8.6 D²PAK (SMD 2L STD-ST) type A package information

Figure 44. D²PAK (SMD 2L STD-ST) type A package outline



0079457_22_type A

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Table 23. D²PAK (SMD 2L STD-ST) mechanical data

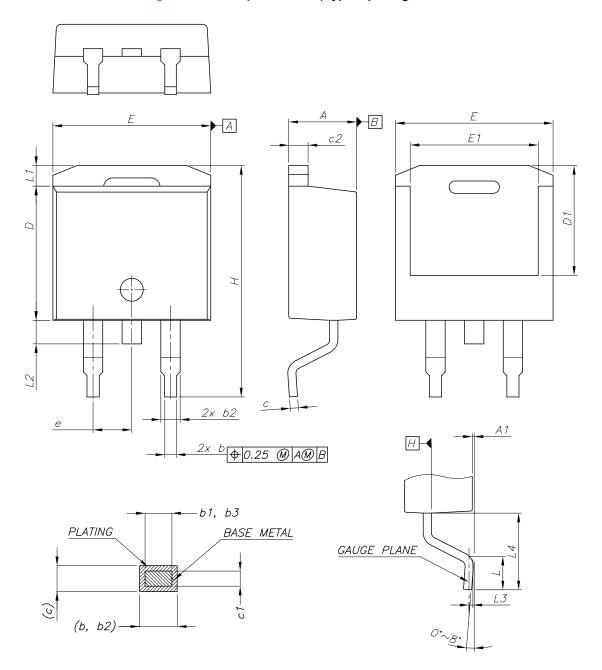
Dim.	mm			
Dilli.	Min.	Тур.	Max.	
А	4.40		4.60	
A1	0.03		0.23	
b	0.70		0.93	
b2	1.14		1.70	
С	0.45		0.60	
c2	1.23		1.36	
D	8.95		9.35	
D1	7.50	7.75	8.00	
D2	1.10	1.30	1.50	
Е	10		10.40	
E1	8.50	8.70	8.90	
E2	6.85	7.05	7.25	
е		2.54		
e1	4.88		5.28	
Н	15		15.85	
J1	2.49		2.69	
L	2.29		2.79	
L1	1.27		1.40	
L2	1.30		1.75	
R		0.4		
V2	0°		8°	

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8.7 D²PAK (ASE) type B package information

Figure 45. D²PAK (ASE subcon) type B package outline



0079457_23_type B

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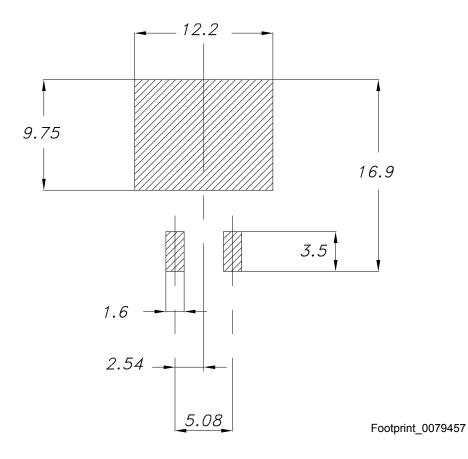
Table 24. D²PAK (ASE) type B mechanical data

Dim.	mm		
Dim.	Min.	Тур.	Max.
Α	4.36		4.56
A1	0		0.25
b	0.70		0.90
b1	0.51		0.89
b2	1.17		1.37
b3	1.36		1.46
С	0.38		0.694
c1	0.38		0.534
c2	1.19		1.34
D	8.60		9.00
D1	6.90		7.50
E	10.15		10.55
E1	8.10		8.70
е		2.54	
Н	15.00		15.60
L	1.90		2.50
L1			1.65
L2			1.78
L3		0.25	
L4	4.78		5.28

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Figure 46. D²PAK recommended footprint (dimensions are in mm)

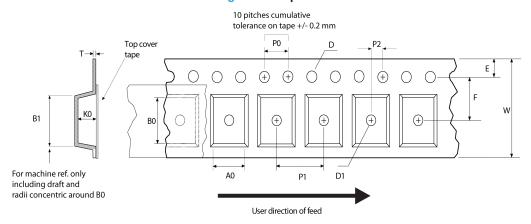


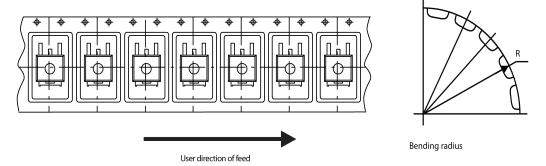
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8.8 D²PAK and DPAK packing information

Figure 47. Tape outline



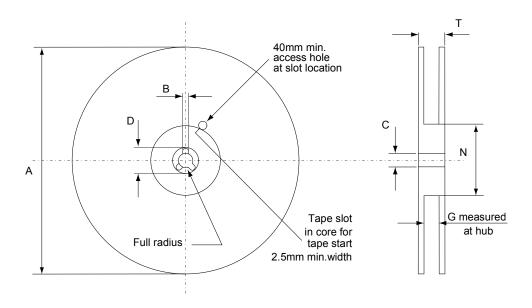


AM08852v1

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Figure 48. Reel outline



AM06038v1

Table 25. D²PAK tape and reel mechanical data

Таре			Reel		
Dim.	mm		Dim.	mı	m
Dilli.	Min.	Max.	Dim.	Min.	Max.
A0	10.5	10.7	А		330
В0	15.7	15.9	В	1.5	
D	1.5	1.6	С	12.8	13.2
D1	1.59	1.61	D	20.2	
Е	1.65	1.85	G	24.4	26.4
F	11.4	11.6	N	100	
K0	4.8	5.0	Т		30.4
P0	3.9	4.1			
P1	11.9	12.1	Base quantity		1000
P2	1.9	2.1	Bulk quantity		1000
R	50				
Т	0.25	0.35			
W	23.7	24.3			

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Table 26. DPAK tape and reel mechanical data

Таре			Reel		
Dim.	mm		mm Dim.	ı	nm
Dilli.	Min.	Max.	Dilli.	Min.	Max.
A0	6.8	7	Α		330
В0	10.4	10.6	В	1.5	
B1		12.1	С	12.8	13.2
D	1.5	1.6	D	20.2	
D1	1.5		G	16.4	18.4
E	1.65	1.85	N	50	
F	7.4	7.6	Т		22.4
K0	2.55	2.75			
P0	3.9	4.1	Bas	e qty.	2500
P1	7.9	8.1	Bull	k qty.	2500
P2	1.9	2.1			
R	40				
Т	0.25	0.35			
W	15.7	16.3			

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9 Ordering information

Table 27. Order codes

	Order codes						
Part number	TO-220 (single gauge)	TO-220 (dual gauge)	DPAK	D²PAK	TO-220FP	Output voltages	
L7805C	L7805CV	L7805CV-DG	L7805CDT-TR	L7805CD2T-TR	L7805CP	5 V	
L7805AB	L7805ABV	L7805ABV-DG		L7805ABD2T-TR	L7805ABP	5 V	
L7805AC	L7805ACV	L7805ACV-DG		L7805ACD2T-TR	L7805ACP	5 V	
L7806C	L7806CV	L7806CV-DG		L7806CD2T-TR		6 V	
L7806AB	L7806ABV	L7806ABV-DG		L7806ABD2T-TR		6 V	
L7806AC	L7806ACV	L7806ACV-DG				6 V	
L7808C	L7808CV	L7808CV-DG		L7808CD2T-TR		8 V	
L7808AB	L7808ABV	L7808ABV-DG		L7808ABD2T-TR		8 V	
L7808AC	L7808ACV	L7808ACV-DG				8 V	
L7885C	L7885CV					8.5 V	
L7809C	L7809CV	L7809CV-DG		L7809CD2T-TR	L7809CP	9 V	
L7809AB	L7809ABV	L7809ABV-DG		L7809ABD2T-TR		9 V	
L7809AC	L7809ACV					9 V	
L7812C	L7812CV	L7812CV-DG		L7812CD2T-TR	L7812CP	12 V	
L7812AB	L7812ABV	L7812ABV-DG		L7812ABD2T-TR		12 V	
L7812AC	L7812ACV	L7812ACV-DG		L7812ACD2T-TR		12 V	
L7815C	L7815CV	L7815CV-DG		L7815CD2T-TR	L7815CP	15 V	
L7815AB	L7815ABV	L7815ABV-DG		L7815ABD2T-TR		15 V	
L7815AC	L7815ACV	L7815ACV-DG		L7815ACD2T-TR		15 V	
L7818C	L7818CV	L7818CV-DG				18 V	
L7824C	L7824CV	L7824CV-DG		L7824CD2T-TR	L7824CP	24 V	
L7824AB	L7824ABV	L7824ABV-DG				24 V	
L7824AC	L7824ACV	L7824ACV-DG				24 V	

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Revision history

Table 28. Document revision history

Date	Revision	Changes
21-Jun-2004	12	Document updating.
03-Aug-2006	13	Order codes has been updated and new template.
19-Jan-2007	14	D²PAK mechanical data has been updated and add footprint data.
31-May-2007	15	Order codes has been updated.
29-Aug-2007	16	Added Table 1 in cover page.
11-Dec-2007	17	Modified: Table 27.
06-Feb-2008	18	Added: TO-220 mechanical data Figure 38 on page 38 , Figure 39 on page 39, and Table 23 on page 37. Modified: Table 27 on page 58.
18-Mar-2008	19	Added: Table 29: DPAK mechanical data on page 50, Table 30: Tape and reel DPAK mechanical data on page 52. Modified: Table 27 on page 58.
26-Jan-2010	20	Modified Table 1 on page 1 and Table 23 on page 37, added: Figure 38 on page 38 and Figure 39 on page 39, Figure 40 on page 45 and Figure 41 on page 45.
04-Mar-2010	21	Added notes Figure 38 on page 38.
08-Sep-2010	22	Modified Table 27 on page 58.
23-Nov-2010	23	Added: TJ = 25 °C test condition in DVO on Table 3, 4, 5, 6, 7, 8 and Table 9.
16-Sep-2011	24	Modified title on page 1.
30-Nov-2011	25	Added: order codes L7805CV-DG, L7806CV-DG, L7808ABV-DG, L7812CV-DG and L7815CV-DG Table 27 on page 58.
08-Feb-2012	26	Added: order codes L7805ACV-DG, L7805ABV-DG, L7806ABV-DG, L7808CV-DG, L7809CV-DG, L7812ACV-DG, L7818CV-DG, L7824CV-DG Table 27 on page 58.
27-Mar-2012	27	Added: order codes L7812ABV-DG, L7815ABV-DG Table 27 on page 58.
27-Apr-2012	28	Modified: VI = 10.4 to 23 V ==> VI = 11.4 to 23 V test condition value Line regulation Table 6 on page 13.
10-May-2012	29	Added: order codes L7806ACV-DG, L7808ACV-DG, L7815ACV-DG, L7824ABV-DG and L7824ACV-DG Table 27 on page 58.
19-Sep-2012	30	Modified load regulation units from V to mV in Table 3 to Table 9.
12-Mar-2013	31	Modified: VO output voltage at 25 °C min. value 14.4 V Table 16 on page 23.
04-Mar-2014	32	Part numbers L78xx, L78xxC, L78xxAB, L78xxAC changed to L78. Removed TO-3 package. Updated the description in cover page, Section 2: Pin configuration, Section 3: Maximum ratings, Section 4: Test circuits, Section 5: Electrical characteristics, Section 6: Application information, Section 8: Package information and Table 27: Order codes. Added Section 9: Packaging mechanical data. Minor text changes.
26-Feb-2016	33	Updated Section 8: Package information. Minor text changes.
28-Nov-2016	34	Updated Section 9: "Ordering information". Minor text changes.
25-May-2018	35	Updated D²PAK package Section 8.7 D²PAK (ASE) type B package information.
17-Sep-2018	36	Updated Figure 29. Dropout voltage vs junction temperature.
16-Oct-2024	37	Updated Table 4

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